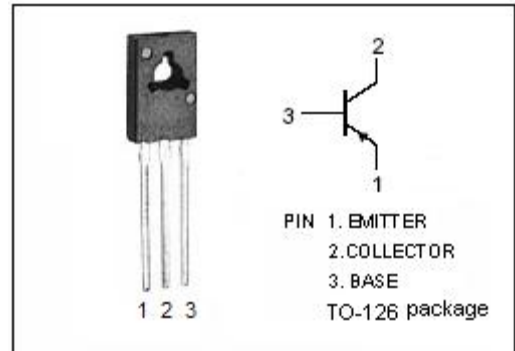


**isc Silicon PNP Power Transistor**
**2SA1096A**
**DESCRIPTION**

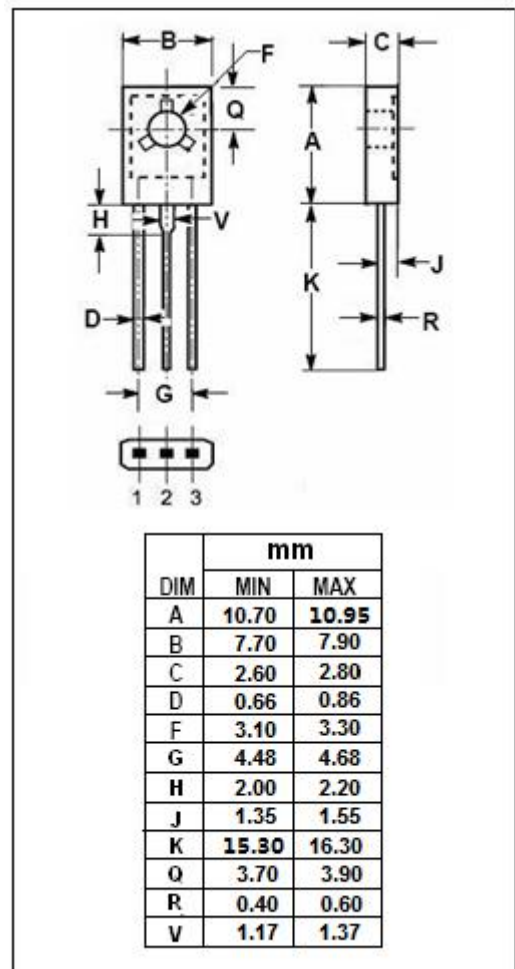
- High Collector-Emitter Breakdown Voltage-  
 $V_{(BR)CEO} = -60V$  (Min)
- Good Linearity of  $h_{FE}$
- Complement to Type 2SC2497A
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**APPLICATIONS**

- Designed for low-frequency power amplification


**ABSOLUTE MAXIMUM RATINGS(Ta=25°C)**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	-70	V
$V_{CEO}$	Collector-Emitter Voltage	-60	V
$V_{EBO}$	Emitter-Base Voltage	-5	V
$I_C$	Collector Current-Continuous	-2	A
$I_{CM}$	Collector Current-Peak	-3	A
$P_C$	Collector Power Dissipation @ $T_a=25^\circ C$	1.2	W
	Total Power Dissipation @ $T_C=25^\circ C$	5	
$T_J$	Junction Temperature	150	°C
$T_{stg}$	Storage Temperature Range	-55~150	°C



**isc Silicon PNP Power Transistor****2SA1096A****ELECTRICAL CHARACTERISTICS**T<sub>c</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -2mA; I <sub>B</sub> = 0	-60			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = -1mA; I <sub>E</sub> = 0	-70			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -1.5A; I <sub>B</sub> = -0.15A			-1.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = -1.5A; I <sub>B</sub> = -0.15A			-1.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -20V; I <sub>E</sub> = 0			-1	μ A
I <sub>CEO</sub>	Collector Cutoff Current	V <sub>CE</sub> = -10V; I <sub>B</sub> = 0			-100	μ A
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-10	μ A
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -5V	80		220	
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>E</sub> = 0.5A; V <sub>CB</sub> = -5V; f= 200MHz		150		MHz
C <sub>OB</sub>	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = -20V; f= 1.0MHz		55		pF

◆ **h<sub>FE</sub> Classifications**

Q	R
80-160	120-220

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